

### Features

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses
- Short turn-off time
- Hermetic metal cases with ceramic insulators

$I_{T(AV)}$	<b>1520A</b>
$V_{DRM}/V_{RRM}$	<b>1100 ~ 1400V</b>
$t_q$	<b>12 ~ 28μs</b>
$I_{TSM}$	<b>18.0 kA</b>

### Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters
- AC motor speed control
- General power switching applications

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		$T_j(°C)$	VALUE			UNIT
					Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	$T_C=55°C$	125			1520	A
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage Repetitive peak reverse voltage	$t_p=10ms$		125	1100		1400	V
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state current Repetitive peak reverse current	at $V_{DRM}$ at $V_{RRM}$		125			100	mA
$I_{TSM}$	Surge on-state current	10ms half sine wave		125			18	kA
$I^2t$	$I^2t$ for fusing coordination	$V_R=0.6V_{RRM}$					1620	$A^2s \cdot 10^3$
$V_{TO}$	Threshold voltage			125			1.63	V
$r_T$	On-state slope resistance						0.25	mΩ
$V_{TM}$	Peak on-state voltage	$I_{TM}=3000A, F=26kN$		25			3.20	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$		125			1000	V/μs
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ to 2500A Gate pulse $t_r \leq 0.5\mu s, I_{GM}=1.5A$		125			1500	A/μs
$Q_r$	Recovery charge	$I_{TM}=1000A, t_p=4000\mu s,$ $di/dt=-20A/\mu s, V_R=100V$		125		105	120	μC
$t_q$	Circuit commutated turn-off time	$I_{TM}=1000A, t_p=4000\mu s, V_R=100V$ $dv/dt=30V/\mu s, di/dt=-20A/\mu s$		125	12		28	μs
$I_{GT}$	Gate trigger current	$V_A=12V, I_A=1A$		25	30		300	mA
$V_{GT}$	Gate trigger voltage				0.8		3.0	V
$I_H$	Holding current				20		400	mA
$I_L$	Latching current						1000	mA
$V_{GD}$	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$		125			0.3	V
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. double side cooled Clamping force 26kN					0.018	°C/W
$R_{th(c-h)}$	Thermal resistance case to heat sink						0.004	
$F_m$	Mounting force				21		30	kN
$T_{vj}$	Junction temperature				-40		125	°C
$T_{stg}$	Stored temperature				-40		140	°C
$W_t$	Weight					590		g
Outline	P12a							

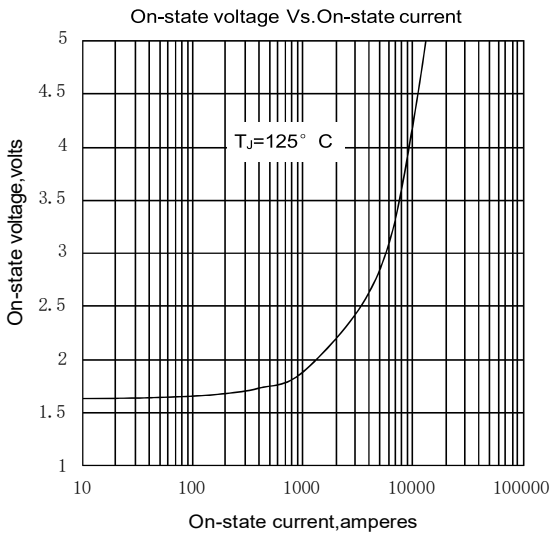


Fig. 1

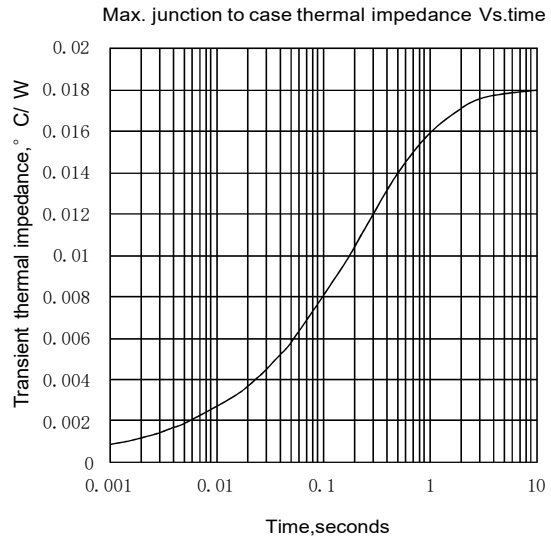


Fig. 2

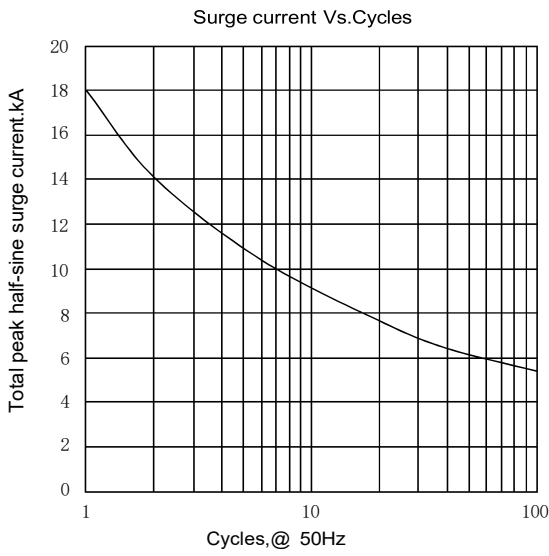


Fig. 3

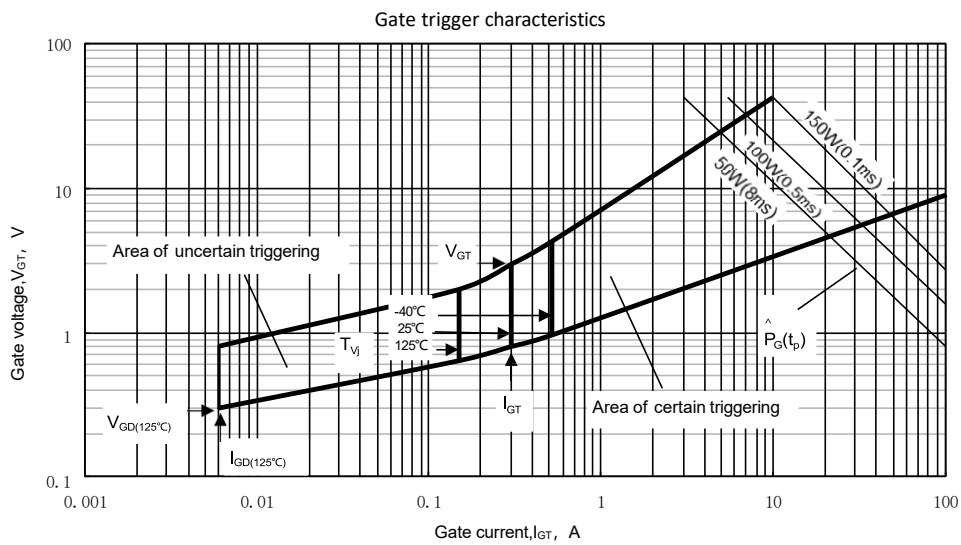
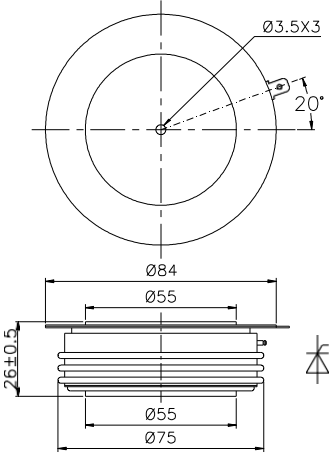


Fig. 4

**Outline:**



Nlps reserves the right to change specifications without notice.